L Number	Hits	Search Text	DB	Time stamp
1	68	(island-like adj semiconductor\$2)same (base underl\$4 undercoat\$4)	USPAT;	2004/09/03 20:09
_			US-PGPUB	
2	119	(island\$1like island adj like)near5 (base underl\$4 undercoat\$4)	USPAT;	2004/09/03 20:19
,	74	((:-14011:1:-1	US-PGPUB	2004/00/02 20:15
3	74	((island\$1like island adj like) near5 (base underl\$4 undercoat\$4)) and	USPAT; US-PGPUB	2004/09/03 20:15
		(lcd electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj transistor\$2)	03-r0r0b	
4	26	(aluminum near2 oxide "Al.sub.2O.sub.3" aluminum adj nitride adj oxide	USPAT;	2004/09/03 20:11
·	20	"AlN.sub.xO.sub.1-x" nitride near2 aluminum "AlN.sub.x" AlSiON	US-PGPUB	200 1703700 20111
		LaSiON ((aluminum) near2 (rare adj earth)) AlSiON LaSiON boron		
		near2 nitride)and (((island\$11ike island adj like)near5 (base underl\$4		
		undercoat\$4)) and (lcd electroluminescent display\$2 soi		
į		silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
_		transistor\$2))		
5	140	(island\$1like island adj like )and (base underl\$4 undercoat\$4)	EPO; JPO;	2004/09/03 20:14
	11	/ /' 1	DERWENT	2004/00/02 20:15
6	11	((island\$1like island adj like) and (base underl\$4 undercoat\$4)) and	EPO; JPO;	2004/09/03 20:15
		(lcd electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj transistor\$2)	DERWENT	
7	2	(island\$1like island adj like )near5 (aluminum near2 oxide	USPAT;	2004/09/03 20:23
<i>'</i>	4	"Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x"	US-PGPUB	2004/05/05 20:25
		nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2	00.0.02	
		(rare adj earth)) AlSiON LaSiON boron near2 nitride)		
8	3	(island\$1like island adj like )and (aluminum near2 oxide	EPO; JPO;	2004/09/03 20:21
		"Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x"	DERWENT	
į		nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2		
		(rare adj earth)) AlSiON LaSiON boron near2 nitride)		
9	95	(soi silicon\$1on\$1insulator\$2 silicon adj insulat\$4)and (island-like adj	USPAT;	2004/09/03 20:23
10	1	semiconductor\$2)and (base underl\$4 undercoat\$4)	US-PGPUB	2004/00/02 20:22
10	1	(soi silicon\$1on\$1insulator\$2 silicon adj insulat\$4)and (island-like adj semiconductor\$2)and (base underl\$4 undercoat\$4)	EPO; JPO; DERWENT	2004/09/03 20:23
11	103	(((pattern\$4 etch\$4 taper tapering tapered)near5(aluminum near2 oxide	USPAT;	2004/09/03 20:27
	105	"Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x"	US-PGPUB	2004/05/05 20:27
		nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2		
		(rare adj earth)) AlSiON LaSiON boron near2 nitride))near17(substrate		
		translucent plastic quartz glass))and (lcd electroluminescent display\$2		
		soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
		transistor\$2)		
12	64	((( thick thicker thinner)near5(aluminum near2 oxide "Al.sub.2O.sub.3"	USPAT;	2004/09/03 20:26
		aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x" nitride near2	US-PGPUB	
		aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2 (rare adjearth)) AlSiON LaSiON boron near2 nitride))near17(substrate translucent		
		plastic quartz glass))and (lcd electroluminescent display\$2 soi		
		silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
		transistor\$2)		
13	454	((( thick thicker thinner)near5(alumina ceramic))near17(substrate	USPAT;	2004/09/03 20:27
		translucent plastic quartz glass))and (lcd electroluminescent display\$2	US-PGPUB	
		soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
	- 10	transistor\$2)		
14	643	(((pattern\$4 etch\$4 taper tapering tapered)near5(alumina ceramic	USPAT;	2004/09/03 20:32
		))near17(substrate translucent plastic quartz glass))and (lcd	US-PGPUB	
		electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj transistor\$2)		
15	145	(((pattern\$4 etch\$4 taper tapering tapered)near5(alumina	USPAT;	2004/09/03 20:29
	143	))near17(substrate translucent plastic quartz glass))and (lcd	US-PGPUB	2001/05/05 20:25
		electroluminescent display\$2 soi silicon\$1on\$1insulator\$2 silicon adj2		
		insulator\$2 tft thin adj film adj transistor\$2)		
16	134	(semiconductor with crystal crystalline single adj crystal)and ( ((( thick	USPAT;	2004/09/03 20:30
		thicker thinner)near5(alumina ceramic))near17(substrate translucent	US-PGPUB	
		plastic quartz glass))and (lcd electroluminescent display\$2 soi		
		silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
		transistor\$2))		

17	10	(((pattern\$4 etch\$4 taper tapering tapered)near5(aluminum near2 oxide	EPO; JPO;	2004/09/03 20:33
		"Al.sub.2O.sub.3" aluminum adj nitride adj oxide "AlN.sub.xO.sub.1-x"	DERWENT	
		nitride near2 aluminum "AlN.sub.x" AlSiON LaSiON ((aluminum) near2		
		(rare adj earth)) AlSiON LaSiON boron near2 nitride))and(substrate		,
		translucent plastic quartz glass))and (lcd electroluminescent display\$2		
		soi silicon\$1on\$1insulator\$2 silicon adj2 insulator\$2 tft thin adj film adj		
		transistor\$2)		